

NL17SZ125

Non-Inverting 3-State Buffer

The NL17SZ125 is a high performance non-inverting buffer operating from a 1.65 V to 5.5 V supply.

Features

- Extremely High Speed: t_{PD} 2.6 ns (typical) at $V_{CC} = 5.0$ V
- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Overvoltage Tolerant Inputs and Outputs
- LVTTL Compatible – Interface Capability With 5.0 V TTL Logic with $V_{CC} = 3.0$ V
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- 3-State OE Input is Active-Low
- Replacement for NC7SZ125
- Chip Complexity = 36 FETs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

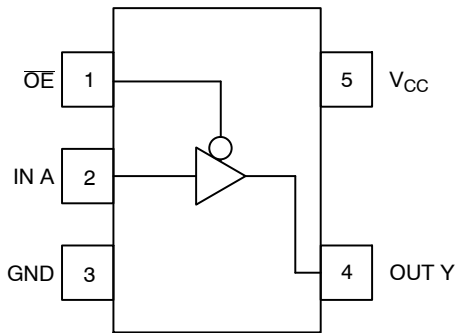


Figure 1. Pinout (Top View)

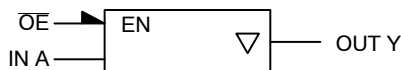


Figure 2. Logic Symbol

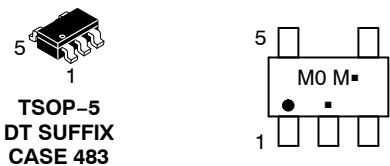
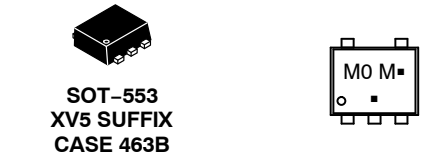
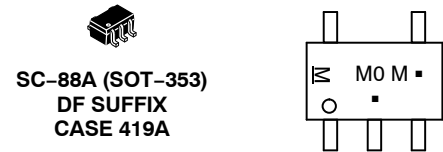
| PIN ASSIGNMENT | |
|----------------|-----------------|
| 1 | \overline{OE} |
| 2 | IN A |
| 3 | GND |
| 4 | OUT Y |
| 5 | V_{CC} |



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MARKING DIAGRAMS



M0 = Specific Device Code
M = Date Code
▪ = Pb-Free Package

(*Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

FUNCTION TABLE

| OE Input | A Input | Y Output |
|----------|---------|----------|
| L | L | L |
| L | H | H |
| H | X | Z |

X = Don't Care

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

NL17SZ125

MAXIMUM RATINGS

| Symbol | Parameter | Value | Units |
|----------------------|---|------------------------|-------|
| V _{CC} | DC Supply Voltage | -0.5 to +7.0 | V |
| V _{IN} | DC Input Voltage | -0.5 to +7.0 | V |
| V _{OUT} | DC Output Voltage | -0.5 to +7.0 | V |
| I _{IK} | DC Input Diode Current | -50 | mA |
| I _{OK} | DC Output Diode Current | -50 | mA |
| I _{OUT} | DC Output Sink Current | ±50 | mA |
| I _{CC} | DC Supply Current per Supply Pin | ±100 | mA |
| T _{STG} | Storage Temperature Range | -65 to +150 | °C |
| T _L | Lead Temperature, 1 mm from Case for 10 Seconds | 260 | °C |
| T _J | Junction Temperature Under Bias | +150 | °C |
| θ _{JA} | Thermal Resistance (Note 1) SC-88A/SOT-553 TSOP-5 | 350 230 | °C/W |
| P _D | Power Dissipation in Still Air at 85°C | 150 | mW |
| MSL | Moisture Sensitivity | Level 1 | |
| F _R | Flammability Rating Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in | |
| V _{ESD} | ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4) | > 2000 > 200 N/A | V |
| I _{LATCHUP} | Latchup Performance Above V _{CC} and Below GND at 125°C (Note 5) | ±100 | mA |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace with no air flow.
2. Tested to EIA/JESD22-A114-A.
3. Tested to EIA/JESD22-A115-A.
4. Tested to JESD22-C101-A.
5. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Units |
|---------------------------------|---|------------------|-----------------------|-------|
| V _{CC} | DC Supply Voltage | 1.65 | 5.5 | V |
| V _{IN} | DC Input Voltage | 0 | 5.5 | V |
| V _{OUT} | DC Output Voltage | 0 | 5.5 | V |
| T _A | Operating Temperature Range | -55 | +125 | °C |
| t _r , t _f | Input Rise and Fall Time V _{CC} = 1.8 V ±0.15 V V _{CC} = 2.5 V ±0.2 V V _{CC} = 3.0 V ±0.3 V V _{CC} = 5.0 V ±0.5 V | 0 0 0 0 | 20 20 10 5.0 | ns/V |

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

| Junction Temperature °C | Time, Hours | Time, Years |
|-------------------------|-------------|-------------|
| 80 | 1,032,200 | 117.8 |
| 90 | 419,300 | 47.9 |
| 100 | 178,700 | 20.4 |
| 110 | 79,600 | 9.4 |
| 120 | 37,000 | 4.2 |
| 130 | 17,800 | 2.0 |
| 140 | 8,900 | 1.0 |

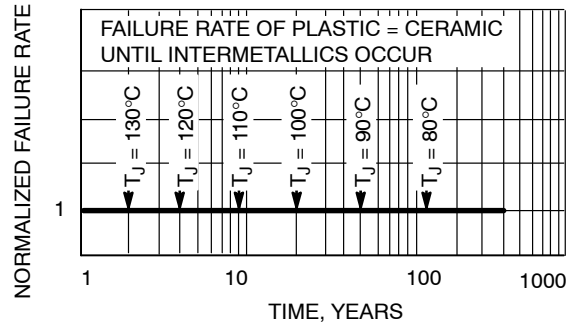


Figure 3. Failure Rate vs. Time Junction Temperature

DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | V _{CC} (V) | T _A = 25°C | | | -55°C ≤ T _A ≤ 125°C | | Units | Condition |
|------------------|--|----------------------------------|---|--------------------------------------|---|---|---|-------|--|
| | | | Min | Typ | Max | Min | Max | | |
| V _{IH} | High-Level Input Voltage | 1.65 to 1.95 2.3 to 5.5 | 0.75 V _{CC} 0.7 V _{CC} | | | 0.75 V _{CC} 0.7 V _{CC} | | V | |
| V _{IL} | Low-Level Input Voltage | 1.65 to 1.95 2.3 to 5.5 | | | 0.25 V _{CC} 0.3 V _{CC} | | 0.25 V _{CC} 0.3 V _{CC} | V | |
| V _{OH} | High-Level Output Voltage V _{IN} = V _{IH} | 1.65 1.8 2.3 3.0 4.5 | 1.55 1.7 2.2 2.9 4.4 | 1.65 1.8 2.3 3.0 4.5 | | 1.55 1.7 2.2 2.9 4.4 | | V | I _{OH} = -100 μA |
| | | 1.65 2.3 3.0 3.0 4.5 | 1.29 1.9 2.4 2.3 3.8 | 1.52 2.15 2.80 2.68 4.20 | | 1.29 1.9 2.4 2.3 3.8 | | V | I _{OH} = -4 mA I _{OH} = -8 mA I _{OH} = -16 mA I _{OH} = -24 mA I _{OH} = -32 mA |
| V _{OL} | Low-Level Output Voltage V _{IN} = V _{IL} | 1.65 1.8 2.3 3.0 4.5 | | 0.0 0.0 0.0 0.0 0.0 | 0.1 0.1 0.1 0.1 0.1 | | 0.1 0.1 0.1 0.1 0.1 | V | I _{OL} = 100 μA |
| | | 1.65 2.3 3.0 3.0 4.5 | | 0.08 0.10 0.15 0.22 0.22 | 0.24 0.30 0.40 0.55 0.55 | | 0.24 0.30 0.40 0.55 0.55 | V | I _{OL} = 4 mA I _{OL} = 8 mA I _{OL} = 16 mA I _{OL} = 24 mA I _{OL} = 32 mA |
| I _{IN} | Input Leakage Current | 0 to 5.5 | | | ±0.1 | | ±1.0 | μA | V _{IN} = 5.5 V or GND |
| I _{OZ} | 3-State Output Leakage | 1.65 to 5.5 | | | ±0.5 | | ±5.0 | μA | V _{IN} = V _{IH} or V _{IL} 0 V ≤ V _{OUT} ≤ 5.5 V |
| I _{OFF} | Power Off Leakage Current | 0 | | | 1.0 | | 10 | μA | V _{IN} = 5.5 V or V _{OUT} = 5.5 V |
| I _{CC} | Quiescent Supply Current | 5.5 | | | 1.0 | | 10 | μA | V _{IN} = 5.5 V or GND |

NL17SZ125

AC ELECTRICAL CHARACTERISTICS ($t_R = t_F = 3.0$ ns)

| Symbol | Parameter | Condition | V _{CC} (V) | T _A = 25°C | | | -55°C ≤ T _A ≤ 125°C | | Units |
|--------------------------------------|---|---|------------------------|-----------------------|-----|------------|--------------------------------|------------|-------|
| | | | | Min | Typ | Max | Min | Max | |
| t _{PLH} t _{PHL} | Propagation Delay AN to YN (Figures 4 and 5, Table 1) | R _L = 1 MΩ C _L = 15 pF | 1.8 ± 0.15 | 2.0 | 9.0 | 10 | 2.0 | 10.5 | ns |
| | | R _L = 1 MΩ C _L = 15 pF | 2.5 ± 0.2 | 1.0 | | 7.5 | 1.0 | 8.0 | |
| | | R _L = 1 MΩ C _L = 15 pF R _L = 500 Ω C _L = 50 pF | 3.3 ± 0.3 | 0.8 1.2 | | 5.2 5.7 | 0.8 1.2 | 5.5 6.0 | |
| | | R _L = 1 MΩ C _L = 15 pF R _L = 500 Ω C _L = 50 pF | 5.0 ± 0.5 | 0.5 0.8 | | 4.5 5.0 | 0.5 0.8 | 4.8 5.3 | |
| t _{PZH} t _{PZL} | Output Enable Time (Figures 6, 7 and 8, Table 1) | R _L = 250 Ω C _L = 50 pF | 1.8 ± 0.15 | 2.0 | 7.6 | 9.5 | 2.0 | 10 | ns |
| | | | 2.5 ± 0.2 | 1.8 | | 8.5 | 1.8 | 9.0 | |
| | | | 3.3 ± 0.3 | 1.2 | | 6.2 | 1.2 | 6.5 | |
| | | | 5.0 ± 0.5 | 0.8 | | 5.5 | 0.8 | 5.8 | |
| t _{PHZ} t _{PLZ} | Output Disable Time (Figures 6, 7 and 8, Table 1) | R _L and R ₁ = 500 Ω C _L = 50 pF | 1.8 ± 0.15 | 2.0 | 8.0 | 10 | 2.0 | 10.5 | ns |
| | | | 2.5 ± 0.2 | 1.5 | | 8.0 | 1.5 | 8.5 | |
| | | | 3.3 ± 0.3 | 0.8 | | 5.7 | 0.8 | 6.0 | |
| | | | 5.0 ± 0.5 | 0.3 | | 4.7 | 0.3 | 5.0 | |

CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Condition | Typical | Units |
|------------------|---|--|---------|-------|
| C _{IN} | Input Capacitance | V _{CC} = 5.5 V, V _I = 0 V or V _{CC} | 2.5 | pF |
| C _{OUT} | Output Capacitance | V _{CC} = 5.5 V, V _I = 0 V or V _{CC} | 2.5 | pF |
| C _{PD} | Power Dissipation Capacitance (Note 6) | 10 MHz, V _{CC} = 3.3 V, V _I = 0 V or V _{CC} 10 MHz, V _{CC} = 5.5 V, V _I = 0 V or V _{CC} | 9 11 | pF |

6. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

NL17SZ125

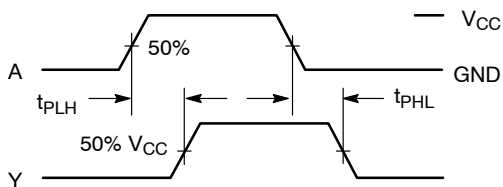
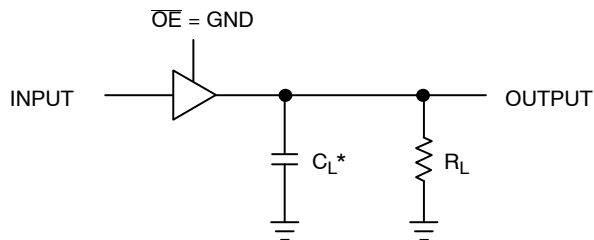
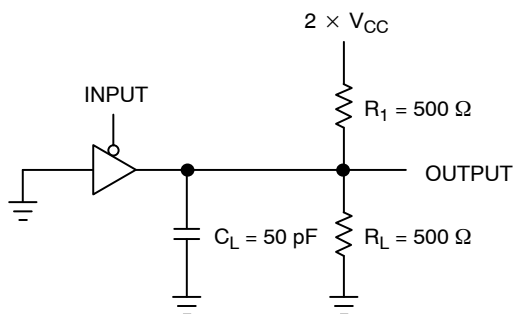


Figure 4. Switching Waveform



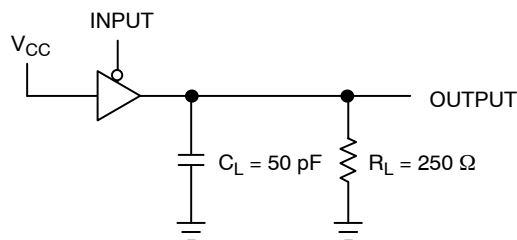
*Includes all probe and jig capacitance.
A 1 MHz square input wave is recommended for propagation delay tests.

Figure 5. t_{PLH} or t_{PHL}



A 1 MHz square input wave is recommended for propagation delay tests.

Figure 6. t_{PZL} or t_{PLZ}



A 1 MHz square input wave is recommended for propagation delay tests.

Figure 7. t_{PZH} or t_{PHZ}

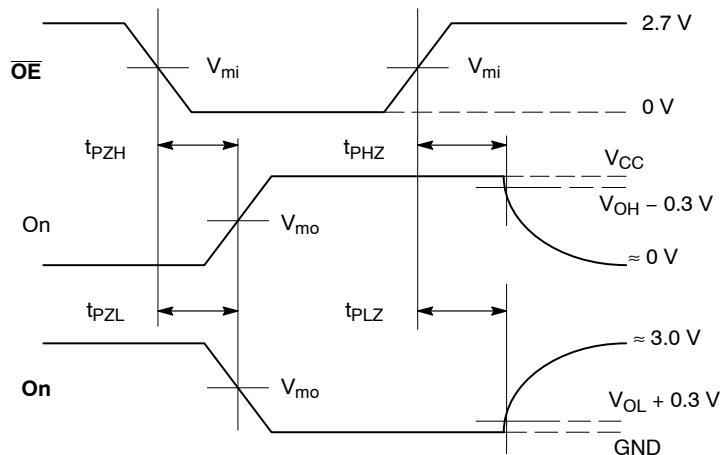


Figure 8. AC Output Enable and Disable Waveform

Table 1. OUTPUT ENABLE AND DISABLE TIMES

$t_R = t_F = 2.5$ ns, 10% to 90%; $f = 1$ MHz; $t_W = 500$ ns

| Symbol | V_{CC} | | |
|----------|-------------------|-------|-------------------|
| | 3.3 V \pm 0.3 V | 2.7 V | 2.5 V \pm 0.2 V |
| V_{mi} | 1.5 V | 1.5 V | $V_{CC}/2$ |
| V_{mo} | 1.5 V | 1.5 V | $V_{CC}/2$ |

NL17SZ125

DEVICE ORDERING INFORMATION

| Device | Package | Shipping† |
|------------------|---------------------------------------|--------------------|
| NL17SZ125DFT2G | SC-88A (SOT-353) (Pb-Free) | 3000 / Tape & Reel |
| NLV17SZ125DFT2G* | SC-88A (SOT-353) (Pb-Free) | 3000 / Tape & Reel |
| NL17SZ125XV5T2G | SOT-553 (Pb-Free) | 4000 / Tape & Reel |
| NL17SZ125DTT1G | TSOP-5 (Pb-Free) | 3000 / Tape & Reel |
| NL17SZ125CMUTCG | UDFN6, 1.0 x 1.0 x 0.35P (Pb-Free) | 3000 / Tape & Reel |

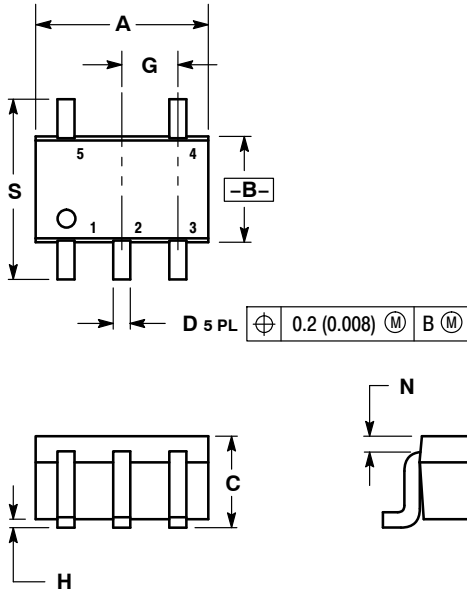
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

NL17SZ125

PACKAGE DIMENSIONS

SC-88A (SC-70-5/SOT-353)
CASE 419A-02
ISSUE L

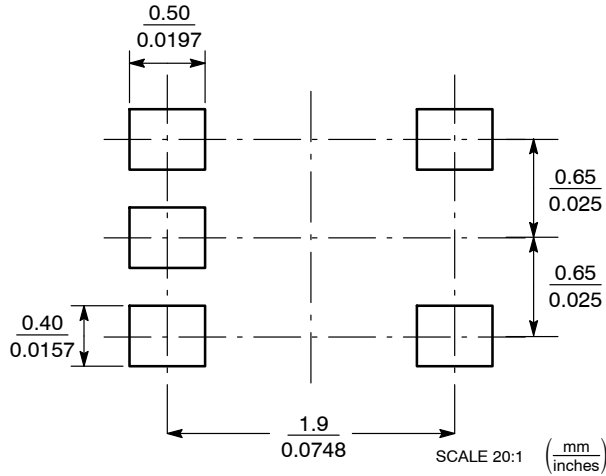


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM | INCHES | | MILLIMETERS | |
|-----|-----------|-------|-------------|------|
| | MIN | MAX | MIN | MAX |
| A | 0.071 | 0.087 | 1.80 | 2.20 |
| B | 0.045 | 0.053 | 1.15 | 1.35 |
| C | 0.031 | 0.043 | 0.80 | 1.10 |
| D | 0.004 | 0.012 | 0.10 | 0.30 |
| G | 0.026 BSC | | 0.65 BSC | |
| H | --- | 0.004 | --- | 0.10 |
| J | 0.004 | 0.010 | 0.10 | 0.25 |
| K | 0.004 | 0.012 | 0.10 | 0.30 |
| N | 0.008 REF | | 0.20 REF | |
| S | 0.079 | 0.087 | 2.00 | 2.20 |

SOLDER FOOTPRINT*

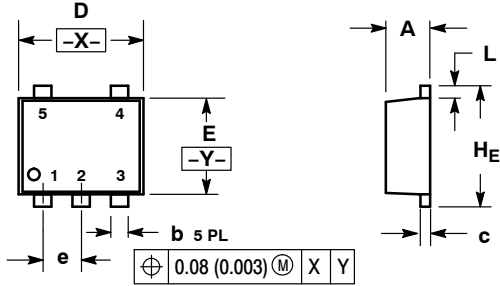


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NL17SZ125

PACKAGE DIMENSIONS

SOT-553, 5 LEAD
CASE 463B
ISSUE B

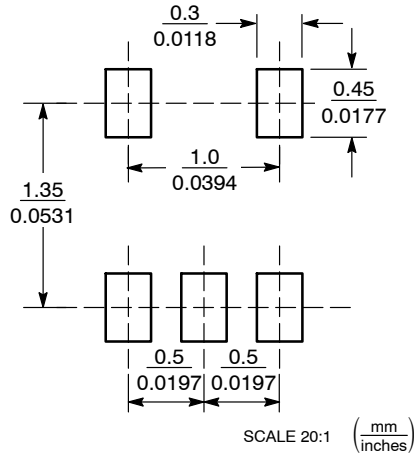


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

| DIM | MILLIMETERS | | | INCHES | | |
|-----|-------------|------|------|-----------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.50 | 0.55 | 0.60 | 0.020 | 0.022 | 0.024 |
| b | 0.17 | 0.22 | 0.27 | 0.007 | 0.009 | 0.011 |
| c | 0.08 | 0.13 | 0.18 | 0.003 | 0.005 | 0.007 |
| D | 1.50 | 1.60 | 1.70 | 0.059 | 0.063 | 0.067 |
| E | 1.10 | 1.20 | 1.30 | 0.043 | 0.047 | 0.051 |
| e | 0.50 BSC | | | 0.020 BSC | | |
| L | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 |
| HE | 1.50 | 1.60 | 1.70 | 0.059 | 0.063 | 0.067 |

SOLDERING FOOTPRINT*

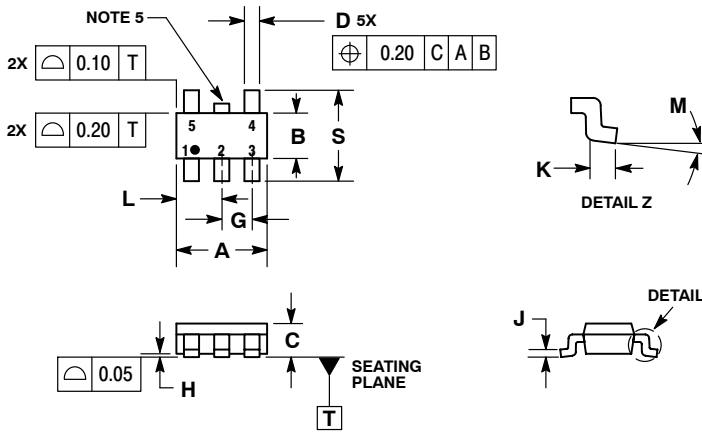


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NL17SZ125

PACKAGE DIMENSIONS

TSOP-5 CASE 483-02 ISSUE H

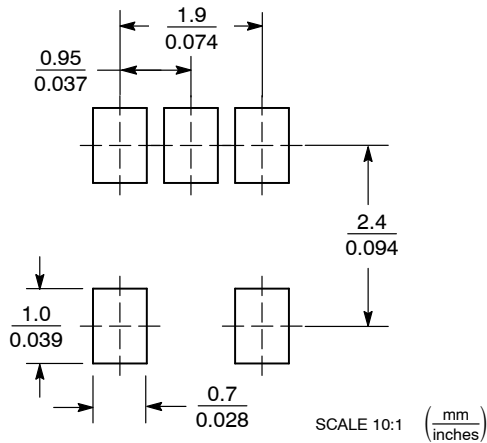


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.
5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

| DIM | MILLIMETERS | |
|-----|-------------|------|
| | MIN | MAX |
| A | 3.00 BSC | |
| B | 1.50 BSC | |
| C | 0.90 | 1.10 |
| D | 0.25 | 0.50 |
| G | 0.95 BSC | |
| H | 0.01 | 0.10 |
| J | 0.10 | 0.26 |
| K | 0.20 | 0.60 |
| L | 1.25 | 1.55 |
| M | 0° | 10° |
| S | 2.50 | 3.00 |

SOLDERING FOOTPRINT*

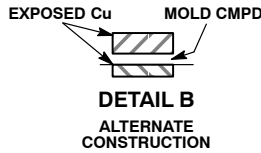
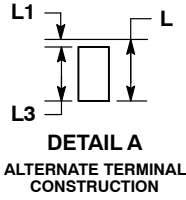
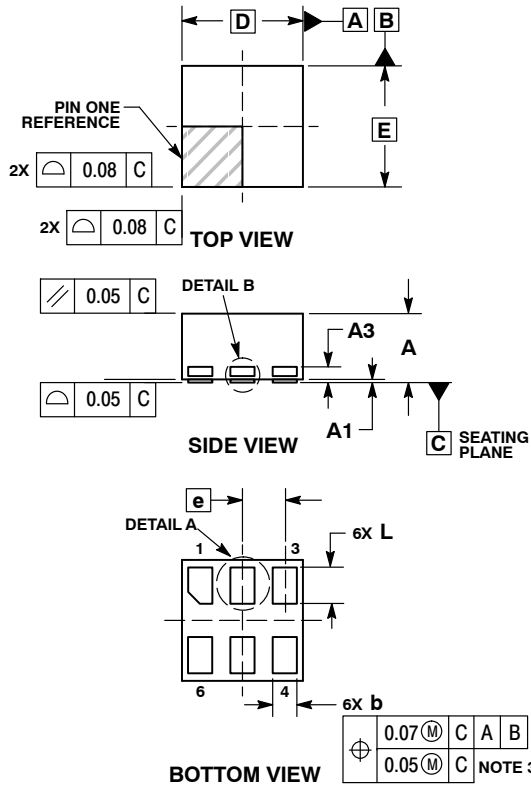


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NL17SZ125

PACKAGE DIMENSIONS

UDFN6, 1x1, 0.35P
CASE 517BX
ISSUE O

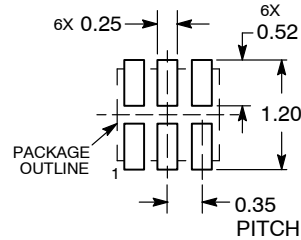


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

| MILLIMETERS | | |
|-------------|------|------|
| DIM | MIN | MAX |
| A | 0.50 | 0.65 |
| A1 | 0.00 | 0.05 |
| A3 | 0.13 | REF |
| b | 0.17 | 0.23 |
| D | 1.00 | BSC |
| E | 1.00 | BSC |
| e | 0.35 | |
| L | 0.20 | 0.40 |
| L1 | --- | 0.15 |
| L3 | 0.26 | 0.33 |

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSION: MILLIMETERS

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Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

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